

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L4	86	(257/220).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:30
L5	83	(257/218).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:39
L6	252	(257/263).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:41
L7	3785	(257/296).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:41
L8	1394	(257/301).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:41
L9	713	(257/302).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:42
L10	939	(257/303).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:42

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L11	580	(257/304).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:43
L12	427	(257/305).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:44
L13	984	(257/328).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:44
L14	1398	(257/330).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:44
L15	610	(257/331).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:44
L16	443	(257/332).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:45
L17	497	(257/374).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 13:46

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L18	13	257/220,218,263,296,301,302,303,304,305,328,330,331,332,374.ccls. and (trench near (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:36
L19	0	257/220,218,263,296,301,302,303,304,305,328,330,331,332,374.ccls. and (trench near (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:36
L20	0	"257"/\$.ccls. and (trench near (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:50
L21	0	"438"/\$.ccls. and (trench near (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:51
L22	0	semiconductor and (trench near (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:51
L23	63	semiconductor and (trench with (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 10:07
L24	97	semiconductor and (trench same (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:51
L25	242	semiconductor and (trench and (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:51

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L26	34	"438"/\$.ccls. and (trench with (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 10:08
L27	52	"438"/\$.ccls. and (trench same (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:51
L28	96	"438"/\$.ccls. and (trench and (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:52
L29	58	"257"/\$.ccls. and (trench with (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:52
L30	86	"257"/\$.ccls. and (trench same (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:52
L31	196	"257"/\$.ccls. and (trench and (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:52
L32	1	(semiconductor and (trench with (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 09:53
L33	0	(semiconductor and (trench with (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave).clm.	USPAT	OR	ON	2006/10/26 09:53
L35	2	((("20050048815") or ("5736760")).PN.	US-PGPUB; USPAT	OR	OFF	2006/10/26 10:17

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L36	42	semiconductor and (trench with (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 10:26
L37	42	semiconductor and (trench with (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave and @ad<="20040107" and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 10:07
L38	144	semiconductor and (trench and (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave and @ad<="20040107" and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 10:26
L39	20	"438"/\$.ccls. and (trench with (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:18
L40	30	"438"/\$.ccls. and (trench same (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 10:08
L41	65	"438"/\$.ccls. and (trench and (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 10:08
L42	141	"257"/\$.ccls. and (trench and (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 10:08
L43	59	"257"/\$.ccls. and (trench same (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:19

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L44	42	"257"/\$.ccls. and (trench with (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 10:09
L45	3	((("6350682") or ("6903023") or ("6500773")).PN.	US-PGPUB; USPAT	OR	OFF	2006/10/26 10:17
L48	0	438/386,243,243.ccls. and (trench near (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:25
L49	5	438/386,243,243.ccls. and (trench and (diffusion adj (layer or film))) and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:51
L50	0	"438"/\$.ccls. and (((trench or vertical) adj (capacitor or transistor)) near (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:32
L51	0	"257"/\$.ccls. and (((trench or vertical) adj (capacitor or transistor)) near (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:30
L52	0	semiconductor and (((trench or vertical) adj (capacitor or transistor)) near (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:30
L53	2	semiconductor and (((trench or vertical) adj (capacitor or transistor)) with (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:31

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L54	3	semiconductor and (((trench or vertical) adj (capacitor or transistor)) same (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:31
L55	15	semiconductor and (((trench or vertical) adj (capacitor or transistor)) and (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:32
L56	11	"438"/\$.ccls. and (((trench or vertical) adj (capacitor or transistor)) and (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:34
L57	2	"438"/\$.ccls. and (((trench or vertical) adj (capacitor or transistor)) same (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:33
L58	1	"438"/\$.ccls. and (((trench or vertical) adj (capacitor or transistor)) with (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:33
L59	15	"257"/\$.ccls. and (((trench or vertical) adj (capacitor or transistor)) and (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:35
L60	3	"257"/\$.ccls. and (((trench or vertical) adj (capacitor or transistor)) same (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:35

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L61	2	"257"/\$.ccls. and (((trench or vertical) adj (capacitor or transistor)) with (diffusion adj (layer or film))) and (first adj conductive) and (second adj conductive) and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:34
L63	2291	257/220,218,263,296,301,302,303,304,305,328,330,331,332,374.ccls. and trench and fill\$4 and gate and isolat\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:36
L64	137	257/220,218,263,296,301,302,303,304,305,328,330,331,332,374.ccls. and trench and fill\$4 and gate and isolat\$5 and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:38
L66	799	(438/386).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 12:45
L67	48	438/386,243,243.ccls. and concave	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:52
L68	1062	438/386,243,243.ccls. and @ad<="20040107"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/10/26 12:55
L69	1394	(257/301).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 13:46
L70	419	(257/393).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 13:46

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L71	226	(257/397).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 13:46
S3	700	(438/386).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 12:45
S7	2	((("20050145912") or ("6207494")).PN.	US-PGPUB; USPAT	OR	OFF	2006/05/02 09:06
S8	843	(438/243).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/16 07:15
S9	728	(438/386).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/03/16 07:16
S13	3	((("20050145912") or ("6207494") or ("5998821")).PN.	US-PGPUB; USPAT	OR	OFF	2006/05/02 09:07
S14	27	("4763181" "4784969" "4792834" "4794434" "5006910" "5012308" "5065273" "5097381" "5119155" "5168366" "5170243" "5170372" "5187566" "5200354" "5250829" "5309008" "5315543" "5349218" "5362663" "5363327" "5372966" "5414285" "5432365" "5442211" "5508541" "5512767" "5528062").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/02 09:18
S15	865	(438/243).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/10/26 09:29